

# PDB-C134

## Silicon Photodiode

The PDB-C134 is a blue enhanced PIN silicon photodiode in a photoconductive mode packaged in a water clear T1 plastic package.

### Applications

Smoke Detectors

Light Pen Detectors

TV & VCR Remotes

Bar Code Detectors

### Features

Large Active Area

Photoconductive

High Speed

Low Cost

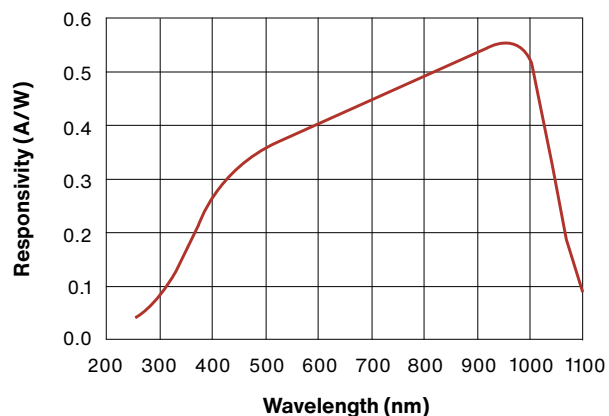
## Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Reverse Voltage	$V_R$	-	100	V
Wavelength Range	-	400	1100	nm
Operating Temperature	$T_{OP}$	-40	+80	°C
Storage Temperature	$T_{STG}$	-55	+100	°C
Package		T1		

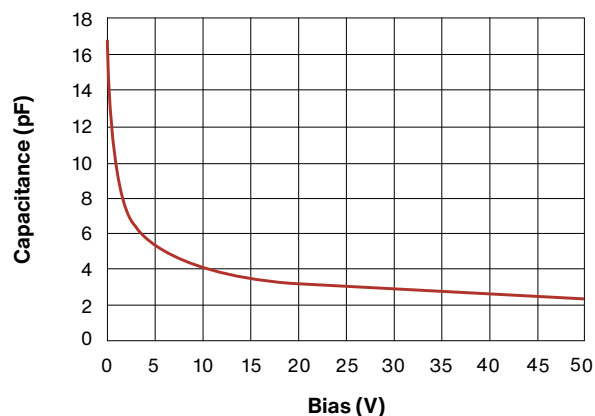
## Typical Electro-Optical Specifications at $T_A=23\text{ }^\circ\text{C}$

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Short Circuit Current	H=100 fc, 2850K	$I_{SC}$	50	60	-	$\mu\text{A}$
Dark Current	$V_R=10\text{V}$	$I_D$	-	2	30	nA
Shunt Resistance	$V_R=10\text{mV}$	$R_{SH}$	0.5	2	-	G $\Omega$
Junction Capacitance	$V_R=10\text{V}; f=1\text{MHz}$	$C_J$	-	6	10	pF
Spectral Application Range	Spot Scan	$\lambda$	400	-	1100	nm
Breakdown Voltage	I=10 $\mu\text{A}$	$V_{BD}$	50	100	-	V
Noise Equivalent Power	$V_R=10\text{V}$ @ $\lambda$ =Peak	NEP	-	$1.8 \times 10^{-13}$	-	W/ $\sqrt{\text{Hz}}$
Response Time	$R_L=1\text{K}\Omega, V_R=50\text{V}$	$T_R$	-	10	-	nS

## Spectral Response

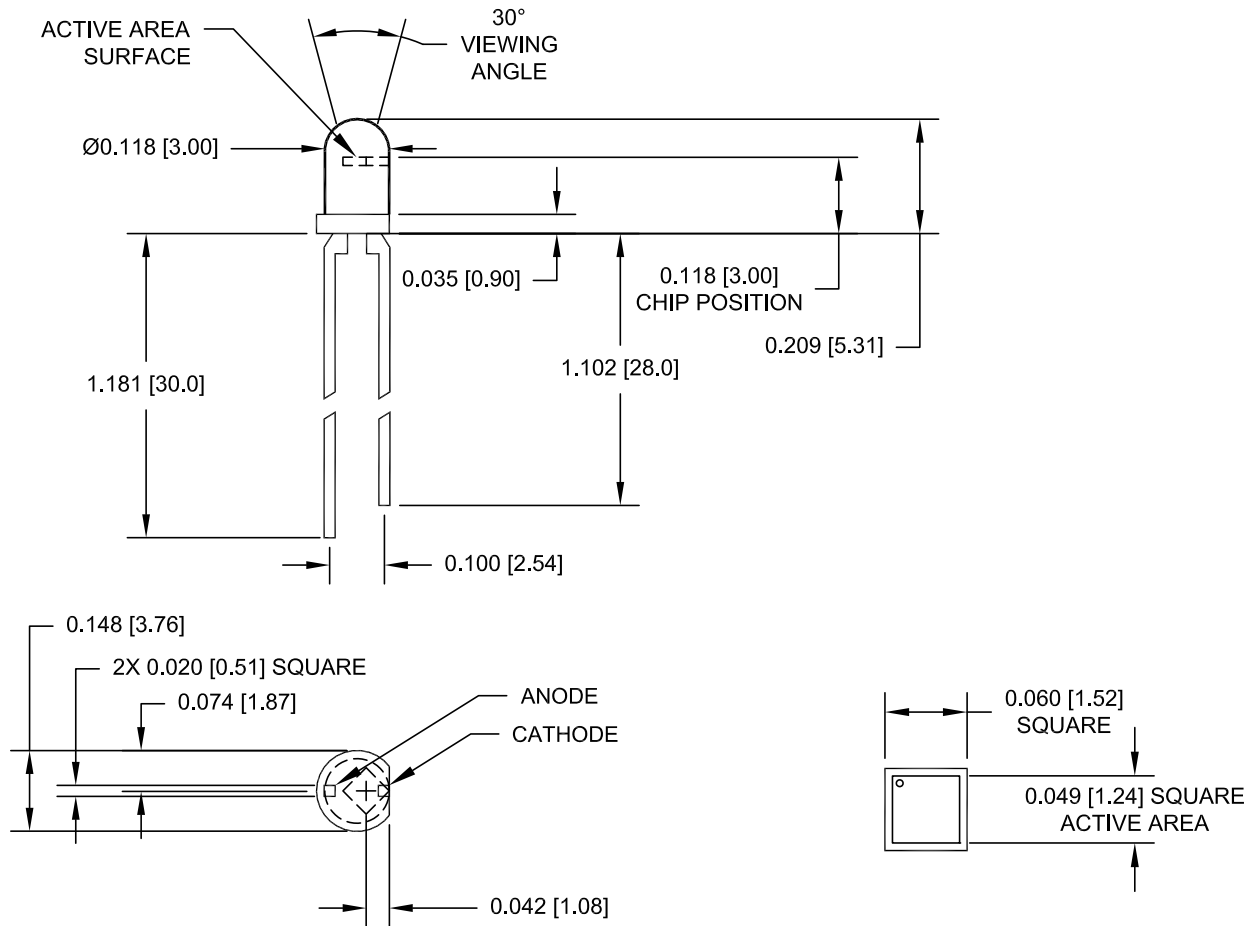


## Capacitance vs Bias



**Mechanical Specifications**

Units are in mm



Soldering Conditions: 260°C 1/16 inch away from case for 3 seconds max.